

NMC6551 1024-Bit (256 × 4) Static RAM

General Description

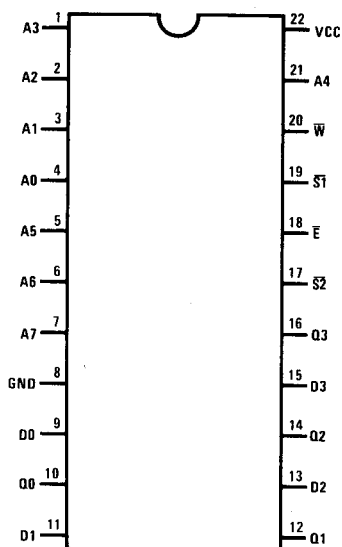
The NMC6551 is a static CMOS random access read/write memory organized as 256 words of 4 bits each. This device is fabricated with National Semiconductor's silicon-gate CMOS technology and is fully compatible with the TTL environment. Synchronous operation is provided by on-chip address input and data output latches. The ENABLE input serves as the device strobe controlling the latching functions. The I/O terminals when not data output enabled, represent high impedance ports for easy memory expansion.

Features

- Industry standard pinout
- Low data retention voltage — 2V
- Low speed/power product
- TTL compatible — all inputs and outputs
- TRI-STATE® outputs for bus operation
- High output drive
- High noise immunity
- Military temperature range available
- On-chip address registers (latches)
- 22 pin — high density packaging
- Output data latches
- Select latch for microprocessor interface

Connection Diagram

Dual-In-Line Package



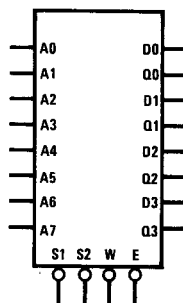
Pin Names

A0-A7
 $\bar{E}$
 $\bar{W}$
 D
 Q
 $\bar{S}_1$, $\bar{S}_2$

Address Inputs
 Chip Enable
 Write Enable
 Data Input
 Data Output
 Chip Selects

TOP VIEW

Logic Symbol



Order Number NMC6551J-2, NMC6551J-9
 or NMC6551J-5

See NS Package J22A

Order Number NMC6551N-5

See NS Package N22A

Functional Description

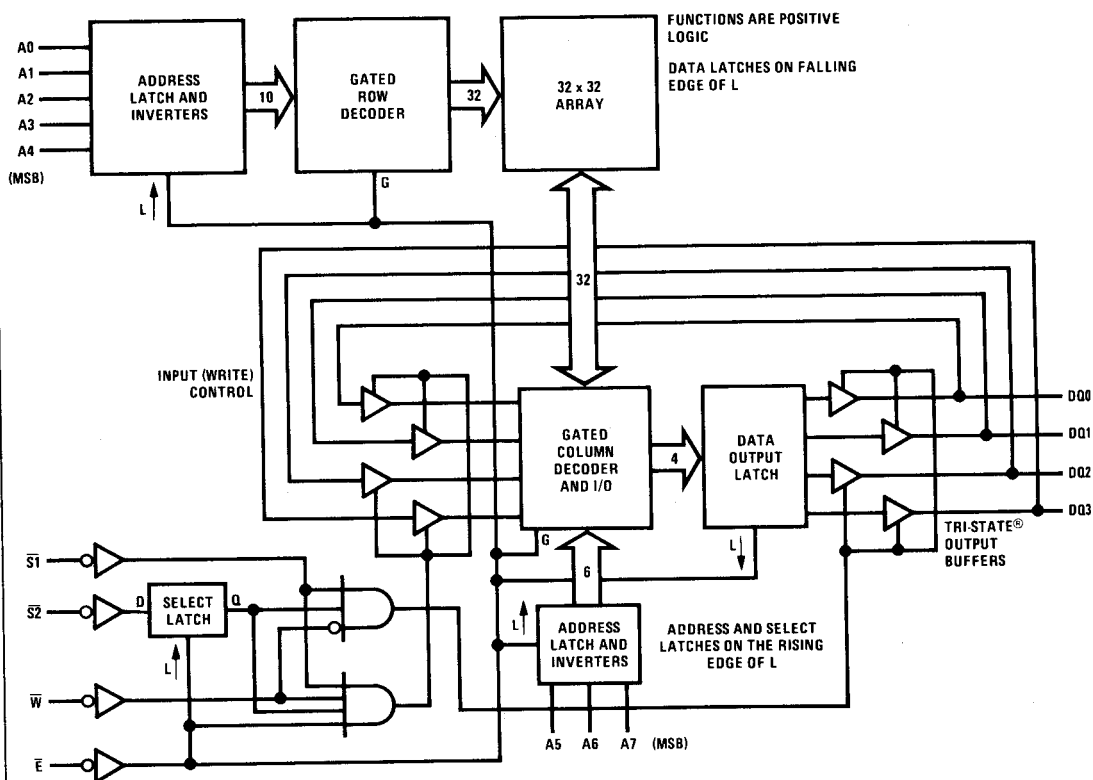
An NMC6551 memory cycle is initiated by the falling edge of the ENABLE ($\bar{E}$) input, which latches the ADDRESS and SELECT 2 ($\bar{S}_2$) information into the on-chip registers. Set-up and hold times must be met. Data output is enabled when the WRITE ($\bar{W}$) input is HIGH and the ENABLE and SELECT 1 inputs are LOW.

When performing a read cycle a minimum ENABLE LOW time is required to assure valid data at the outputs. This minimum LOW time is defined as the device enable access time. A minimum ENABLE HIGH time is required to

return the columns to the HIGH state and to precharge the sense amplifiers in preparation of the next memory cycle.

When performing a write cycle, the minimum ENABLE LOW time is required to enter new data. The write pulse timing is created by the coincident LOW of the WRITE, ENABLE and SELECT 1 inputs. The data set-up and hold times are referenced to the rising edge of the WRITE, ENABLE, or SELECT 1 input, whichever occurs first.

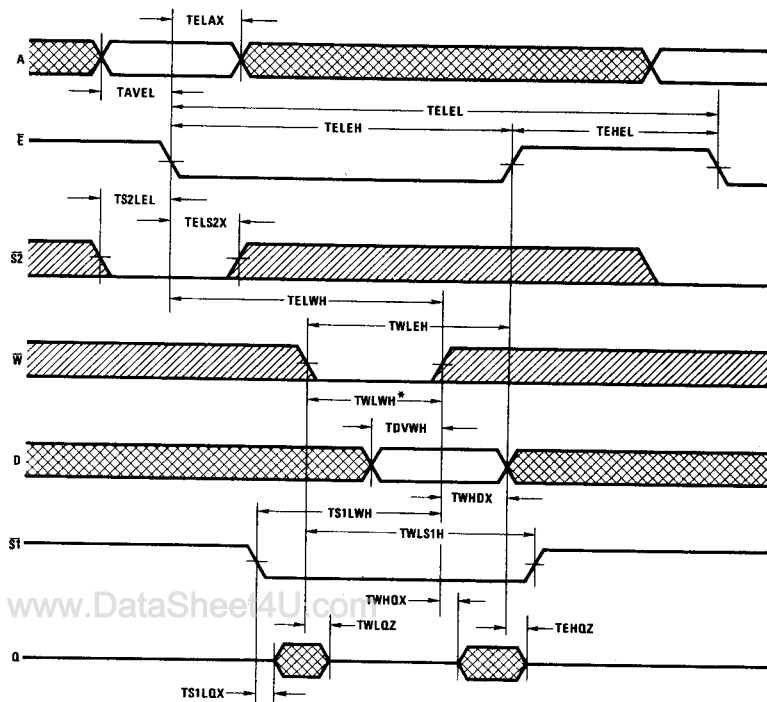
Block Diagram



Write Cycle AC Electrical Characteristics over the operating range

Symbol	Parameter	NMC6551B-9 NMC6551B-2		NMC6551-9 NMC6551-2		NMC6551-5		Units
		Min	Max	Min	Max	Min	Max	
TAVEL	Address Set-up Time	0		0		10		ns
TELAX	Address Hold Time	40		50		70		ns
TWLWH	Write Pulse Width ($\bar{W}$ Low)	120		180		210		ns
TELEL	Read or Write Cycle Time	320		400		500		ns
TELEH	Enable ($\bar{E}$) Minimum Low Time	220		300		350		ns
TS2LEL	Chip Select 2 Set-up Time	0		0		10		ns
TWHDX	Data Hold Time	0		0		0		ns
TELS2X	Chip Select 2 Hold Time	40		50		70		ns
TDVWH	Data Set-up Time	100		150		170		ns
TELWH	Write Pulse Width ($\bar{E}$ and $\bar{W}$ Low)	120		180		210		ns
TEHEL	Enable ($\bar{E}$) Minimum High Time	100		100		150		ns
TWLEH	Write Pulse Width ($\bar{E}$ and $\bar{W}$ Low)	120		180		210		ns
TS1LWH	Chip Select 1 Write Pulse Hold Time	120		180		210		ns
TWLS1H	Chip Select 1 Write Pulse Set-up Time	120		180		210		ns
TS1LQX	Output Enable from $\bar{S}1$		130		150		180	ns
TWLQZ	Output Disable from $\bar{W}$		130		150		180	ns
TWHQX	Output Enable from $\bar{W}$		130		150		180	ns
TEHQZ	Output Disable from $\bar{E}$		130		150		180	ns

Write Cycle Waveforms



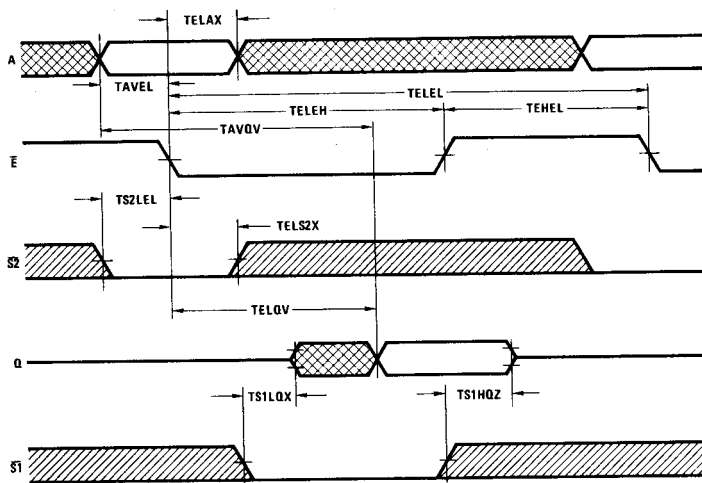
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*TWLWH, the write pulse, is the coincidence low of $\bar{E}$, $\bar{W}$, and $\bar{S}1$ inputs

Read Cycle AC Electrical Characteristics over the operating range

Symbol	Parameter	NMC6551B-9 NMC6551B-2		NMC6551-9 NMC6551-2		NMC6551-5		Units
		Min	Max	Min	Max	Min	Max	
TAVEL	Address Set-up Time	0		0		10		ns
TELAX	Address Hold Time	40		50		70		ns
TELQV	Enable Access Time		220		300		350	ns
TAVQV	Address Access Time		220		300		360	ns
TELEH	Enable (Ē) Minimum Low Time	220		300		350		ns
TELS2X	Chip Select 2 Hold Time	40		50		70		ns
TEHEL	Enable (Ē) Minimum High Time	100		100		150		ns
TELEL	Read or Write Cycle Time	320		400		500		ns
TS1LQX	Chip Select 1 Output Enable Time		130		150		180	ns
TS1HQZ	Chip Select 1 Output Disable Time		130		150		180	ns
TS2LEL	Chip Select 2 Set-up Time	0		0		10		ns

Read Cycle Waveforms



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Absolute Maximum Ratings

Supply Voltage VCC	7V
Voltage at Any Pin	-0.3V to VCC + 0.3V
Storage Temperature Range	-65°C to +150°C
Package Dissipation	500 mW
Lead Temperature (Soldering, 10 seconds)	300°C

Operating Range

	Min	Max
Supply Voltage		
NMC6551B-9	4.5V	5.5V
NMC6551B-2	4.5V	5.5V
NMC6551-9	4.5V	5.5V
NMC6551-2	4.5V	5.5V
NMC6551-5	4.75V	5.25V
Temperature		
NMC6551B-9	-40°C	85°C
NMC6551B-2	-55°C	125°C
NMC6551-9	-40°C	85°C
NMC6551-2	-55°C	125°C
NMC6551-5	0°C	75°C

DC Electrical Characteristics over the operating range, unless otherwise noted

Symbol	Parameter	Conditions	NMC6551B-9, NMC6551B-2 NMC6551-9, NMC6551-2		NMC6551-5		Units
			Min	Max	Min	Max	
VCCDR	Data Retention Supply Voltage	VI = VCC, GND	2.0		2.0		V
ICCSB	Standby Supply Current			10 1(+25°C)		100	μA
ICCOP*	Operating Supply Current	f = 1 MHz, IO = 0, VI = VCC or GND		4		4	mA
ICCDR	Data Retention Supply Current	VCC = 3.0V, IO = 0, VI = VCC or GND		10		100	μA
II	Input Leakage Current	VI = VCC, GND	-1.0	+1.0	-1.0	+1.0	μA
VIL	Input Low Voltage		-0.3	0.8	-0.3	0.8	V
VIH	Input High Voltage		VCC - 2.0	VCC + 0.3	VCC - 2	VCC + 0.3	V
IOZ	Output Leakage Current	VI = VCC, GND	-1.0	+1.0	-1.0	+1.0	μA
VOL	Output Low Voltage	IOL = 3.2 mA		0.4		0.4	V
VOH	Output High Voltage	IOH = -0.4 mA	2.4		2.4		V
CI	Input Capacitance	f = 1 MHz		6		6	pF
CO	Output Capacitance	f = 1 MHz		10		10	pF

* ICCOP is proportional to operating frequency.

AC Test Conditions

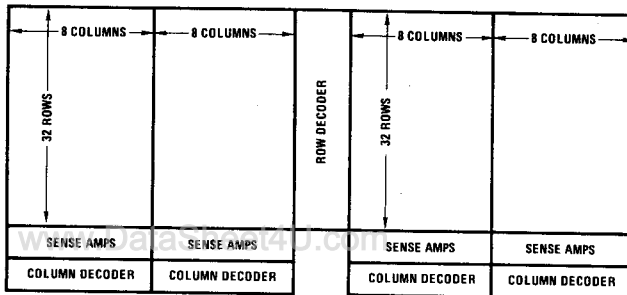
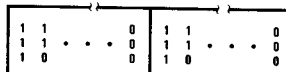
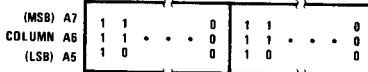
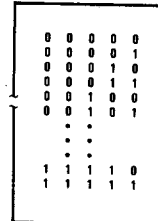
Input Rise and Fall Times: ≤ 20 ns

All Timing Reference Levels: 1/2 VCC

Output Load: 1 TTL Load, 50 pF

NMC6551 Bit Map and Address Decoding

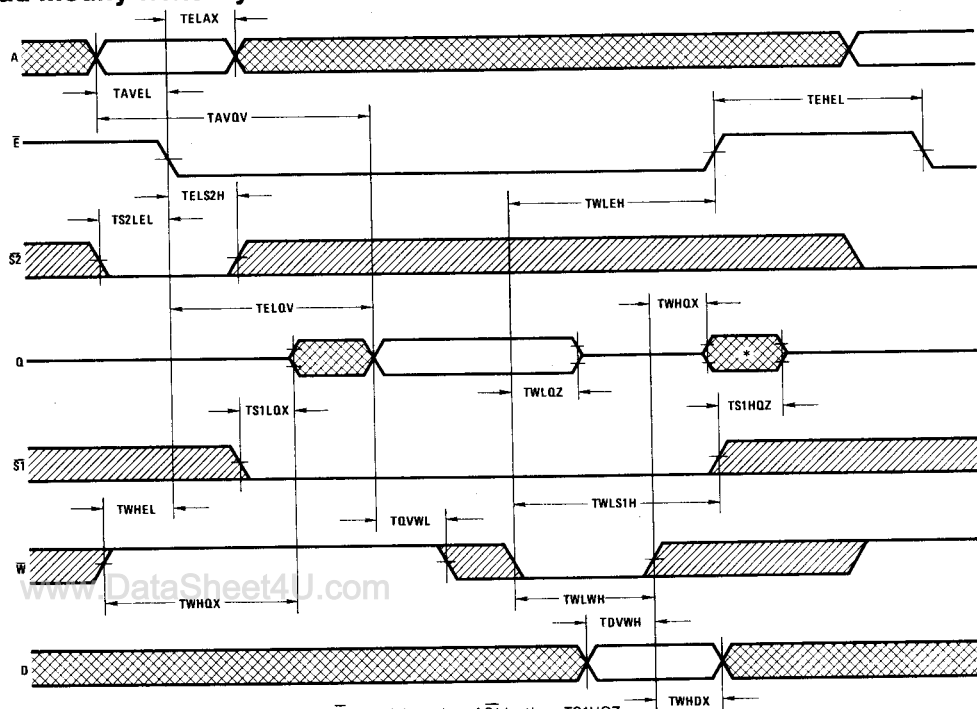
VCC

(MSB) ROWS (LSB)
A4 A3 A2 A1 A0

Read-Modify-Write Cycle AC Electrical Characteristics over the operating range

Symbol	Parameter	NMC6551B-9 NMC6551B-2		NMC6551-9 NMC6551-2		NMC6551-5		Units
		Min	Max	Min	Max	Min	Max	
TAVEL	Address Set-up Time	0		0		10		ns
TELAX	Address Hold Time	40		50		70		ns
TELQV	Enable Access Time		220		300		350	ns
TAVQV	Address Access Time		220		300		360	ns
TWLEH	Write Pulse Width ($\bar{W}$ and $\bar{E}$ Low)	120		180		210		ns
TEHEL	Enable ($\bar{E}$) Minimum High Time	100		100		150		ns
TWLWH	Write Pulse Width ($\bar{W}$ Low)	120		180		210		ns
TELEL	Read or Write Cycle Time	320		400		500		ns
TS1LQX	Chip Select 1 Output Enable Time		130		150		180	ns
TS1HQZ	Chip Select 1 Output Disable Time		130		150		180	ns
TS2LEL	Chip Select 2 Set-up Time	0		0		10		ns
TWHDX	Data Hold Time	0		0		0		ns
TELS2H	Chip Select 2 Hold Time	40		50		70		ns
TWLS1H	Chip Select 1 Write Pulse Set-up Time	120		180		210		ns
TWLQZ	Output Disable from Write ($\bar{W}$)		130		150		180	ns
TDVWH	Data Set-up Time	100		150		170		ns
TQVWL	Data Valid to Write Time	0		0		0		ns
TWHEL	$\bar{W}$ Read Mode Set-up Time	0		0		0		ns
TWHQX	Output Enable from Write ($\bar{W}$)		130		150		180	ns

Read-Modify-Write Cycle Waveforms



* Avoid unwanted output by preceding rising edge of $\bar{W}$ with rising edge of S_1 by time; TS1HQZ